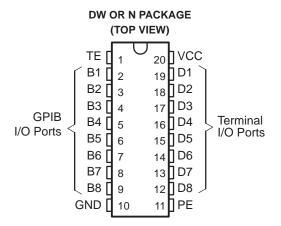
- Meets IEEE Standard 488-1978 (GPIB)
- 8-Channel Bidirectional Transceiver
- Power-Up/Power-Down Protection (Glitch Free)
- High-Speed, Low-Power Schottky Circuitry
- Low Power Dissipation . . . 72 mW Max Per Channel
- Fast Propagation Times . . . 22 ns Max
- High-Impedance pnp Inputs
- Receiver Hysteresis . . . 650 mV Typ
- Open-Collector Driver Output Option
- No Loading of Bus When Device Is Powered Down (V_{CC} = 0)



description

The SN75160B 8-channel general-purpose interface bus (GPIB) transceiver is a monolithic, high-speed, low-power Schottky device designed for two-way data communications over single-ended transmission lines. It is designed to meet the requirements of IEEE Standard 488-1978. The transceiver features driver outputs that can be operated in either the passive-pullup or 3-state mode. If talk enable (TE) is high, these ports have the characteristics of passive-pullup outputs when pullup enable (PE) is low and of 3-state outputs when PE is high. Taking TE low places these ports in the high-impedance state. The driver outputs are designed to handle loads up to 48 mA of sink current.

Output glitches during power up and power down are eliminated by an internal circuit that disables both the bus and receiver outputs. The outputs do not load the bus when $V_{CC} = 0$. When combined with the SN75161B or SN75162B management bus transceivers, the pair provides the complete 16-wire interface for the IEEE-488 bus.

The SN75160B is characterized for operation from 0°C to 70°C.

Function Tables

EACH DRIVER									
	INPUTS								
D	TE	В							
Н	Н	Н	Н						
L	Н	Χ	L						
Н	Χ	L	z†						
Х	L	Χ	z†						

EACH RECEIVER								
INPUTS								
TE	D							
L	Х	L						
L	X	Н						
Н	Х	Z						
	INPUTS	TE PE L X L X						

H = high level, L = low level, X = irrelevant, Z = high impedance

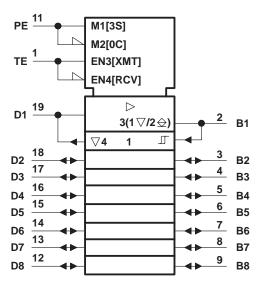


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



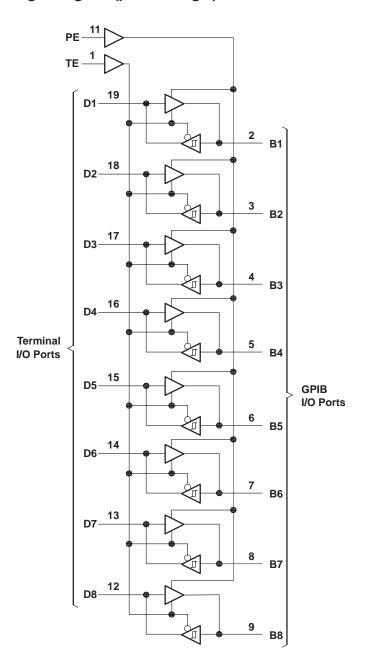
[†]This is the high-impedance state of a normal 3-state output modified by the internal resistors to V_{CC} and GND.

logic symbol[†]



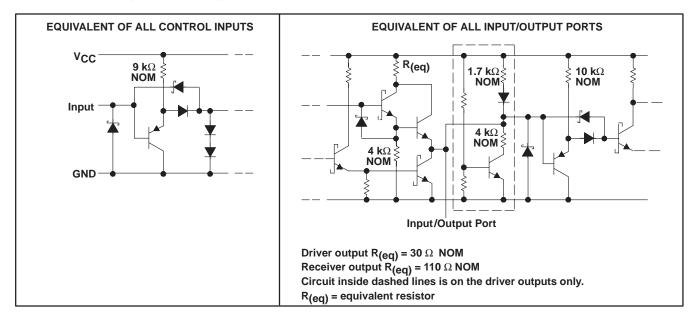
- † This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
- □ Designates 3-state outputs

logic diagram (positive logic)





schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	
Input voltage, V _I	
Low-level driver output current, I _{OL}	100 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range, T _{Stq}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING		
DW	1125 mW	9.0 mW/°C	720 mW		
N	1150 mW	9.2 mW/°C	736 mW		



SN75160B **OCTAL GENERAL-PURPOSE** INTERFACE BUS TRANSCEIVER SLLS004B - OCTOBER 1985 - REVISED MAY 1995

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
High-level input voltage, V _{IH}	gh-level input voltage, V _{IH} 2				V
Low-level input voltage, V _{IL}				0.8	V
High level output ourrent leve	Bus ports with pullups active			-5.2	mA
High-level output current, IOH	Terminal ports			-800	μΑ
Low-level output current, IOL	Bus ports			48	mA
Low-level output current, IOL	Terminal ports			16	IIIA
Operating free-air temperature, TA	0		70	°C	

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TES	MIN	TYP [†]	MAX	UNIT		
VIK	Input clamp voltage		I _I = -18 mA	$I_{\parallel} = -18 \text{ mA}$				V	
V _{hys}	Hysteresis voltage (V _{IT+} - V _{IT-})	Bus	See Figure 8		0.4	0.65		V	
Va	High-level output voltage	Terminal	$I_{OH} = -800 \mu A$	TE at 0.8 V	2.7	3.5		V	
VOH	High-level output voltage	Bus	$I_{OH} = -5.2 \text{ mA},$	PE and TE at 2 V	2.5	3.3		V	
VOL	Low-level output voltage	Terminal	$I_{OL} = 16 \text{ mA},$	TE at 0.8 V		0.3	0.5	V	
VOL	Low-level output voltage	Bus	$I_{OL} = 48 \text{ mA},$	TE at 2 V		0.35	0.5	V	
łį	Input current at maximum input voltage	Terminal	V _I = 5.5 V	V _I = 5.5 V				μΑ	
I _{IH}	High-level input current	Terminal	V _I = 2.7 V			0.1	20	μΑ	
I _I L	Low-level input current	Terminal	V _I = 0.5 V			-10	-100	μΑ	
Vivor	Voltage at bus port		Driver disabled	$I_{I(bus)} = 0$	2.5	3.0	3.7	V	
VI/O(bus)			Driver disabled	$I_{I(bus)} = -12 \text{ mA}$			-1.5	V	
	Current into bus port	Power on		$V_{I(bus)} = -1.5 \text{ V to } 0.4 \text{ V}$	-1.3				
			Driver disabled	$V_{I(bus)} = 0.4 \text{ V to } 2.5 \text{ V}$	0		-3.2		
II/O(bus)				led $V_{I(bus)} = 2.5 \text{ V to } 3.7 \text{ V}$			2.5 -3.2	mA	
, ,				$V_{I(bus)} = 3.7 \text{ V to 5 V}$	0		2.5		
				V _{I(bus)} = 5 V to 5.5 V	0.7		2.5		
		Power off	$V_{CC} = 0$,	$V_{I(bus)} = 0 \text{ to } 2.5 \text{ V}$			-40		
la a	Chart aircuit autaut aurrant	Terminal			-15	-35	-75	A	
los	Short-circuit output current	Bus			-25	-50	-125	mA	
loo	Supply current		No load	Receivers low and enabled		70	90	mA	
ICC	Supply current		INO IOAU	Drivers low and enabled	85 110		110	IIIA	
C _{I/O(bus)}	Bus-port capacitance		$V_{CC} = 0 \text{ to 5 V},$ f = 1 MHz	$V_{I/O} = 0 \text{ to } 2 \text{ V},$		16		pF	

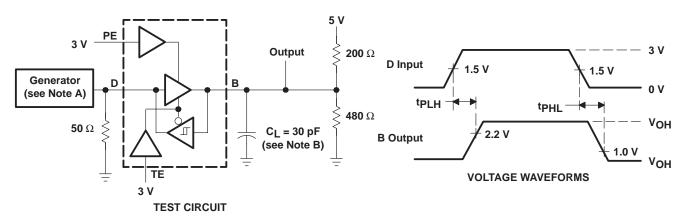
 $[\]dagger$ All typical values are at V_{CC} = 5 V, T_A = 25°C.



switching characteristics, V_{CC} = 5 V, C_L = 15 pF, T_A = 25°C (unless otherwise noted)

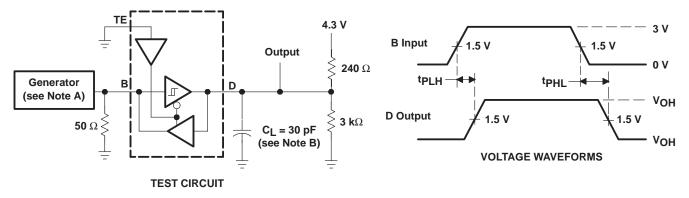
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t PLH	Propation delay time, low- to high-level output	Terminal	Bus	C _L = 30 pF,		14	20	ns
tPHL	Propagation delay time, high- to low-level output	Terminar	Dus	See Figure 1		14	20	113
^t PLH	Propagation delay time, low- to high-level output	Bus	Terminal	C _L = 30 pF,		10	20	ns
^t PHL	Propagation delay time, high- to low-level output	Bus Terminal		See Figure 2		15	22	115
^t PZH	Output enable time to high level					25	35	
^t PHZ	Output disable time from high level]	DLIC	Coo Figure 2		13	22	ns
^t PZL	Output enable time to low level] '-	TE BUS See Figure 3			22	35	ns
tPLZ	Output disable time from low level	1				22	32	
^t PZH	Output enable time to high level					20	30	
^t PHZ	Output disable time from high level	TE TE	Townsians	Can Firmer 4		12	20	
tPZL	Output enable time to low level] '=	Terminal	See Figure 4		23	32	ns
tPLZ	Output disable time from low level	1				19	30	
t _{en}	Output pullup enable time	DE .	Due	Can Figure F		15	22	
^t dis	Output pullup disable time] PE	PE Bus See Figure 5			13	20	ns

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ ns, $Z_{O} =$ 50 Ω .
 - B. C_L includes probe and jig capacitance.

Figure 1. Terminal-to-Bus Test Circuit and Voltage Waveforms

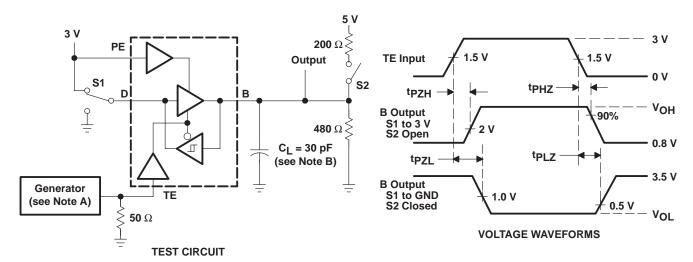


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ ns, $Z_{O} = 50 \Omega$.
 - B. C_L includes probe and jig capacitance.

Figure 2. Bus-to-Terminal Test Circuit and Voltage Waveforms

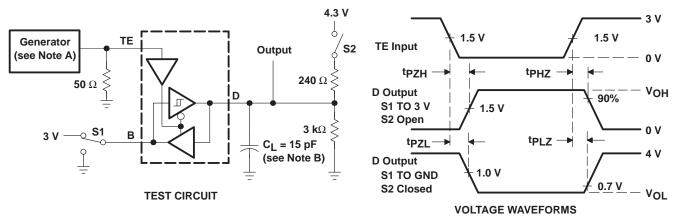


PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{\tilde{\Gamma}} \leq$ ns, $z_{\tilde{C}} =$ 50 Ω .
 - B. C_L includes probe and jig capacitance.

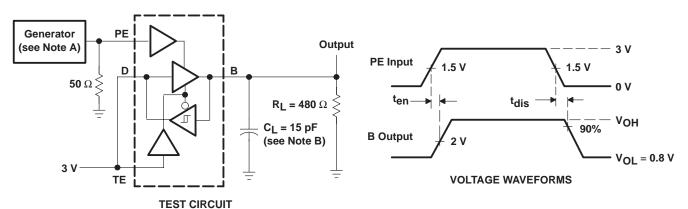
Figure 3. TE-to-Bus Test Circuit and Voltage Waveforms



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ ns, $Z_{O} = 50 \Omega$.
 - B. CL includes probe and jig capacitance.

Figure 4. TE-to-Terminal Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 50% duty cycle, $t_f \leq$ 6 ns, $t_f \leq$ ns, $t_O = 50 \Omega$.

B. CL includes probe and jig capacitance.

Figure 5. PE-to-Bus Pullup Test Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS

TERMINAL I/O PORTS HIGH-LEVEL OUTPUT VOLTAGE vs **HIGH-LEVEL OUTPUT CURRENT** 4 $V_{CC} = 5 V$ T_A = 25°C 3.5 V_{OH} - High-Level Output Voltage - V 3 2.5 2 1.5 1 0.5 0 0 -5 -10 -15 -20 -25 -30 -35 -40 IOH - High-Level Output Current - mA

Figure 6

TERMINAL I/O PORTS LOW-LEVEL OUTPUT VOLTAGE **LOW-LEVEL OUTPUT CURRENT** 0.6 $V_{CC} = 5 V$ T_A = 25°C V_{OL} - Low-Level Output Voltage - V 0.5 0.4 0.3 0.2 0.1

TERMINAL I/O PORTS OUTPUT VOLTAGE

0

0

10

20

30

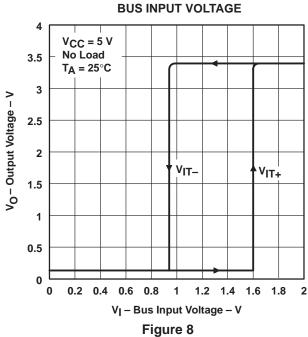
IOL - Low-Level Output Current - mA

Figure 7

40

50

60

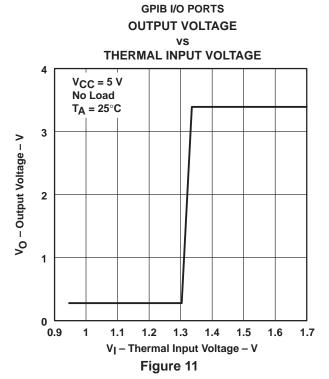




TYPICAL CHARACTERISTICS

GPIB I/O PORTS HIGH-LEVEL OUTPUT VOLTAGE **HIGH-LEVEL OUTPUT CURRENT** 0 $V_{CC} = 5 V$ $T_A = 25^{\circ}C$ VOH - High-Level Output Voltage - V 3 2 0 0 -10-50-20 -40-30-60IOH - High-Level Output Current - mA

Figure 9



GPIB I/O PORTS

LOW-LEVEL OUTPUT VOLTAGE

vs

LOW-LEVEL OUTPUT CURRENT

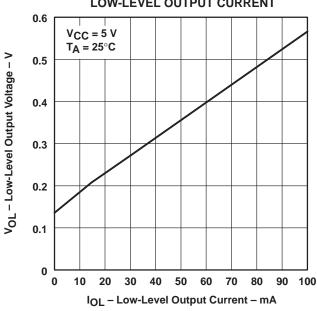
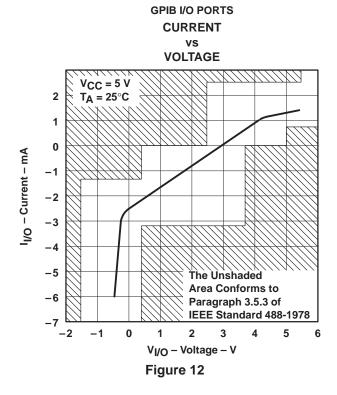


Figure 10







i.com 18-Sep-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75160BDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75160BN	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN75160BNE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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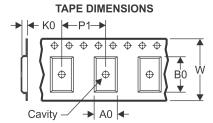
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PACKAGE MATERIALS INFORMATION

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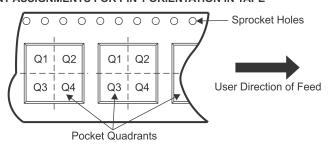
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75160BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN75160BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75160BDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN75160BDWR	SOIC	DW	20	2000	367.0	367.0	45.0

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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